L Number	Hits	Search Text	DB	Time stamp
-	2510	composite near dielectric	USPAT;	2004/08/04 11:53
_			US-PGPUB;	
		(composite near dielectric) and (effective near dielectric near constant)	ЕРО; ЈРО;	
			DERWENT;	
	94		IBM_TDB	
			USPAT;	2004/08/04 09:01
			US-PGPUB;	
			ЕРО; ЈРО;	
			DERWENT;	
]			IBM_TDB	
-	2	((composite near dielectric) and (effective near dielectric near constant))	USPAT;	2004/08/03 19:19
		and (dielectric with ((cubic near boron near nitride) CBN))	US-PGPUB,	
			ЕРО; ЈРО;	
			DERWENT;	
	33	(dielectric with ((cubic near boron near nitride) CBN)) ("6674146").PN.	IBM_TDB	
_			USPAT;	2004/08/04 08:04
			US-PGPUB;	
			ЕРО; ЛРО;	
}			DERWENT;	
	2		IBM_TDB	
_			USPAT;	2004/08/04 08:01
			US-PGPUB;	200 11 00.01
			ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
_	1	"5081053".PN.	USPAT	2004/08/04 07:41
_	5783	((contact near point\$1) gate junction interconnect\$3) near2 surface	USPAT;	2004/08/04 08:04
	3763	near2 substrate	US-PGPUB;	200 1100/01 00:01
			ЕРО; ЛРО;	
			DERWENT;	
			IBM TDB	
_	57	(((contact near point\$1) gate junction interconnect\$3) near2 surface	USPAT;	2004/08/04 09:38
	31	near2 substrate) and ((boron near nitride) CBN)	US-PGPUB;	200 11 00/01 07:50
			ЕРО; ЛРО;	
			DERWENT;	
	49 791	composite near dielectric and ((boron near nitride) CBN) dielectric with ((boron near nitride) CBN)	IBM_TDB	
_			USPAT;	2004/08/04 11:13
			US-PGPUB;	200 1100/01 11110
			ЕРО; ЛРО;	
			DERWENT;	
			IBM TDB	
			USPAT;	2004/08/04 08:59
			US-PGPUB;	200 ,, 50, 50, 50, 50, 50, 50, 50, 50, 50
			ЕРО; ЛРО;	
			DERWENT;	
	3	(dielectric with ((boron near nitride) CBN)) and (((contact near point\$1)	IBM_TDB	
_			USPAT;	2004/08/04 08:59
		gate junction interconnect\$3) near2 surface near2 substrate)	US-PGPUB;	
		gute junction interconnectes) near 2 surface near 2 substitute)	ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
<u> </u>	1331	dielectric same ((boron near nitride) CBN)	USPAT;	2004/08/04 08:59
	1551	diefective same ((voron near munue) CDN)	US-PGPUB;	200 11 001 0 7 00.27
			EPO; JPO;	
-	5	(dielectric same ((boron near nitride) CBN)) and (((contact near point\$1) gate junction interconnect\$3) near2 surface near2 substrate)	DERWENT;	
			IBM TDB	
			USPAT;	2004/08/04 08:59
			US-PGPUB;	2007/00/04 00.39
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
		<u> </u>	םמו וייים	l

-	47	(dielectric same ((boron near nitride) CBN)) and (effective near	USPAT;	2004/08/04 09:01
		dielectric near constant)	US-PGPUB;	
			ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
_	6	09/607,207	USPAT;	2004/08/04 09:39
		,	US-PGPUB;	
]		ЕРО; ЈРО;	
	,			
			DERWENT;	
	_ !		IBM_TDB	
-	8	dielectric near constant near Si3N4	USPAT;	2004/08/04 11:50
			US-PGPUB;	
			ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
l <u>-</u>	2	contact near composite near dielectric	USPĀT;	2004/08/04 11:51
		Toniant near composite near arenewate	US-PGPUB;	2001100.0111.01
			ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
-	2	contact near through near2 composite near dielectric	USPAT,	2004/08/04 11:52
			US-PGPUB;	
			ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
l _	2	(contact near through near2 dielectric near (layer film)) and (composite	USPAT;	2004/08/04 11:54
		near dielectric)	US-PGPUB;	2001/00/01 11.51
		lical dielectric)	-	4
			ЕРО; ЛРО;	,
			DERWENT;	
			IBM_TDB	
-	194	contact near through near2 dielectric near (layer film)	USPAT;	2004/08/04 12:05
			US-PGPUB;	
	}		ЕРО; ЛРО;	
	1		DERWENT;	
			IBM_TDB	
_	4	(contact near through near2 dielectric near (layer film)) and ((boron near	USPĀT;	2004/08/04 11:55
	`	nitride) CBN)	US-PGPUB;	
		murde) ebity	ЕРО; ЛРО;	
			DERWENT;	
ł				
	_		IBM_TDB	2004/00/04 12 00
-	2	first near dielectric near surround\$3 near second near dielectric	USPAT;	2004/08/04 12:08
			US-PGPUB;	
			ЕРО; ЈРО;	
			DERWENT;	
			IBM_TDB	
-	15	first near (insulat\$3 dielectric) near surround\$3 near second near	USPĀT;	2004/08/04 12:21
		(insulat\$3 dielectric)	US-PGPUB;	
		, , , , , , , , , , , , , , , , , , ,	ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
	0	first near (insulat\$3 dialectric) near (theren near nitride) CDN)	USPAT;	2004/08/04 12:20
-	"	first near (insulat\$3 dielectric) near2 ((boron near nitride) CBN) near		2004/06/04 12:20
		surround\$3 near second near (insulat\$3 dielectric)	US-PGPUB;	
	ļ .		ЕРО; ЈРО;	
	1		DERWENT;	
	1		IBM_TDB	
-	41	first near (insulat\$3 dielectric) near (cover\$3 surround\$3 around) near	USPAT;	2004/08/04 12:21
		second near (insulat\$3 dielectric)	US-PGPUB;	
			ЕРО; ЛРО;	
			DERWENT;	
]			
L		<u> </u>	IBM_TDB	<u></u>